

Device Modeling Report

COMPONENTS:

DIODE/ SCHOTTKY RECTIFIER / STANDARD

PART NUMBER: 30GWJ2CZ47C

MANUFACTURER: TOSHIBA

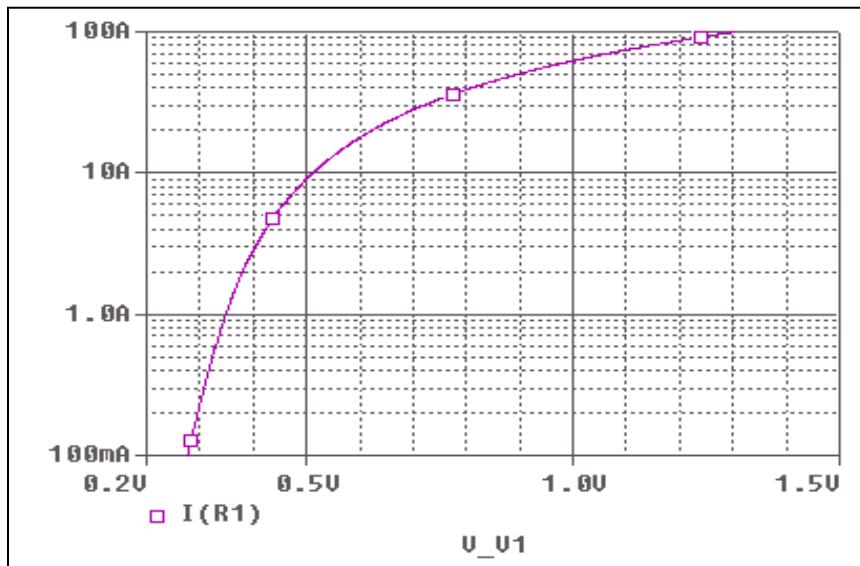


Bee Technologies Inc.

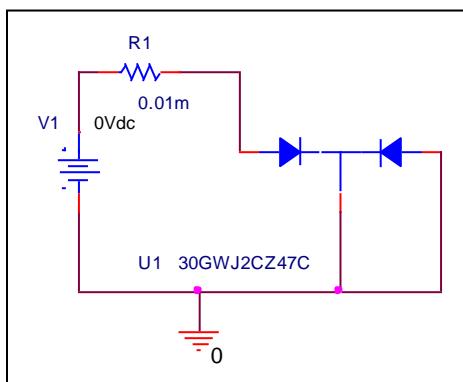
| PSpice model parameter | Model description |
|------------------------|---|
| IS | Saturation Current |
| N | Emission Coefficient |
| RS | Series Resistance |
| IKF | High-injection Knee Current |
| CJO | Zero-bias Junction Capacitance |
| M | Junction Grading Coefficient |
| VJ | Junction Potential |
| ISR | Recombination Current Saturation Value |
| BV | Reverse Breakdown Voltage(a positive value) |
| IBV | Reverse Breakdown Current(a positive value) |
| TT | Transit Time |
| EG | Energy-band Gap |

Forward Current Characteristic

Circuit Simulation Result

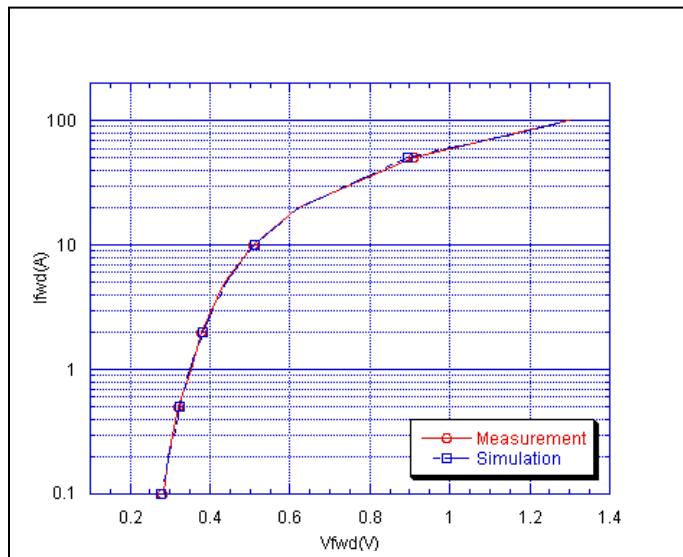


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

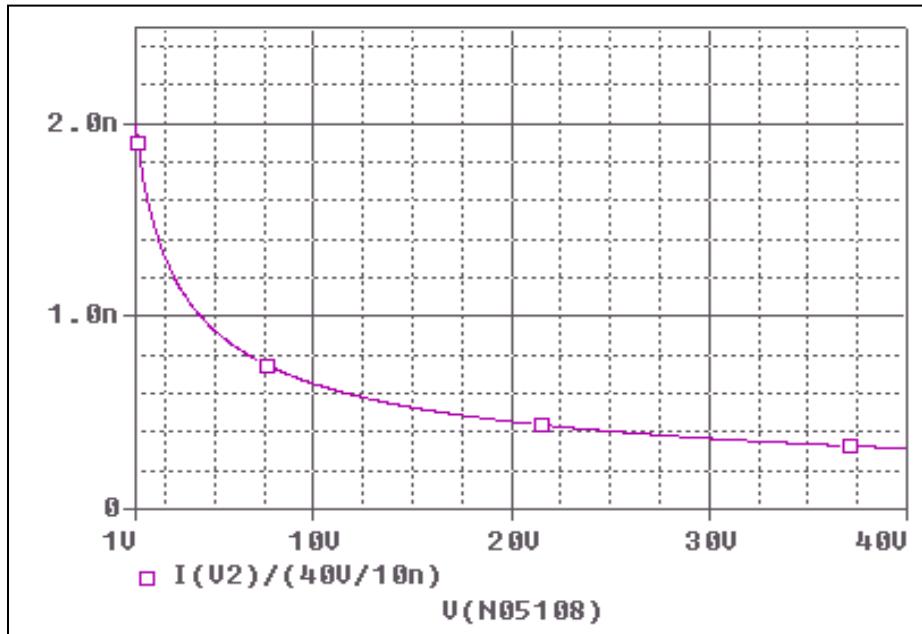


Simulation Result

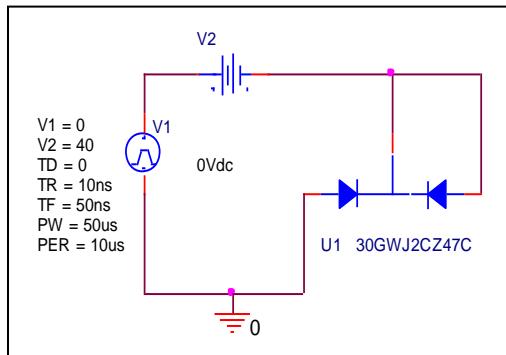
| Ifwd(A) | Vfwd(V) Measurement | Vfwd(V) Simulation | %Error |
|---------|------------------------|-----------------------|--------|
| 0.1 | 0.280 | 0.277 | -1.11 |
| 0.2 | 0.295 | 0.296 | 0.31 |
| 0.5 | 0.320 | 0.324 | 1.19 |
| 1 | 0.352 | 0.350 | -0.65 |
| 2 | 0.380 | 0.380 | 0.03 |
| 5 | 0.435 | 0.441 | 1.38 |
| 10 | 0.510 | 0.512 | 0.39 |
| 20 | 0.620 | 0.622 | 0.39 |
| 50 | 0.910 | 0.896 | -1.58 |
| 100 | 1.300 | 1.308 | 0.64 |

Junction Capacitance Characteristic

Circuit Simulation Result

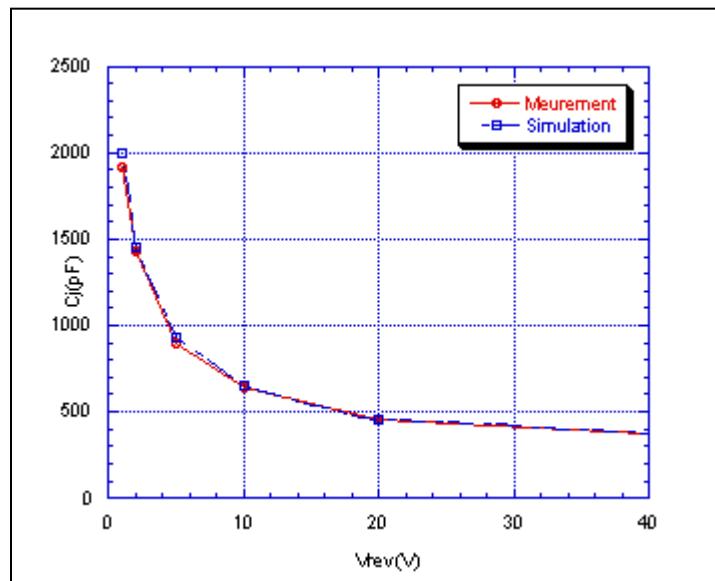


Evaluation Circuit



Comparison Graph

Circuit Simulation Result



Simulation Result

| $V_{rev}(V)$ | $C_j(pF)$ Measurement | $C_j(pF)$ Simulation | %Error |
|--------------|--------------------------|-------------------------|--------|
| 1 | 1920.00 | 1995.00 | 3.91 |
| 2 | 1430.00 | 1450.00 | 1.40 |
| 5 | 900.00 | 926.60 | 2.96 |
| 10 | 645.00 | 650.60 | 0.87 |
| 20 | 450.00 | 453.90 | 0.87 |
| 40 | 310.00 | 316.80 | 2.19 |